TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7PA19FU

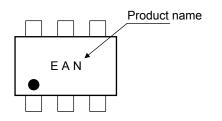
Chip Select Decoder

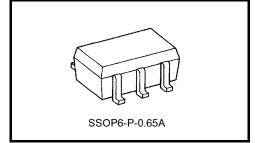
Features

Operating voltage range:	V _{CC} = 1.4~3.6 V
High-speed operation:	t _{pd} = 3.3 ns (max) at V _{CC} = 3.0~3.6 V
	t_{pd} = 3.9 ns (max) at V _{CC} = 2.3~2.7 V
	t_{pd} = 8.0 ns (max) at V _{CC} = 1.65~1.95 V
	t_{pd} = 10.0 ns (max) at V _{CC} = 1.4~1.6 V
High-level output current:	
	I_{OH}/I_{OL} = ±24 mA (min) at V _{CC} = 3.0 V
	I_{OH}/I_{OL} = ±18 mA (min) at V _{CC} = 2.3 V
	I_{OH}/I_{OL} = ±4 mA (min) at V _{CC} = 1.4 V
3.6 V tolerant inputs	

3.6 V power down protection outputs

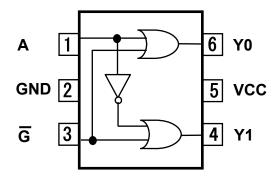
Marking





Weight: 0.0068 g (typ.)

Pin Assignment (top view)



Truth Table

Inp	outs	Outp	outs	
Enable	Select	Y0	Y1	Selected Output
IJ	А	fU	τı	
Н	Х	Н	Н	None
L	L	L	Н	Y0
L	Н	Н	L	Y1

X: Don't care

Absolute Maximum Ratings

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~4.6	V
DC output voltage	V _{OUT}	-0.5~4.6 (Note1)	V
De output voltage	V001	-0.5~V _{CC} + 0.5 (Note2)	v
Input diode current	IIK	-50	mA
Output diode current	I _{OK}	-50 (Note3)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	200	mW
DC V _{CC} /ground current	ICC	±100	mA
Storage temperature	T _{stg}	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: V_{CC} = 0 V

Note2: High or Low state. The $\mathsf{I}_{\mathsf{OUT}}$ absolute maximum rating must be adhered to.

Note3: V_{OUT} < GND

Operating Ranges

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	1.4~3.6	V	
Power supply voltage	VCC	1.2~3.6 (Note4)	v	
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	Vour	0~3.6 (Note5)	V	
Output voltage	Vout	0~V _{CC} (Note6)	v	
		±24 (Note7)		
Output Current	I _{OH} /I _{OL}	±18 (Note8)	mA	
		±4 (Note9)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note10)	ns/V	

Note4: Data retention only

Note5: $V_{CC} = 0 V$

Note6: High or Low state

Note7: V_{CC} = 3.0~3.6 V

Note8: V_{CC} = 2.3~2.7 V

Note9: V_{CC} = 1.4~1.9 V

Note10: $V_{IN} = 0.8 \sim 2.0 \text{ V}, \text{ V}_{CC} = 3.0 \text{ V}$

DC Electrical Characteristics (Ta = -40~85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristics	Symbol	Teet (Test Condition		Min	Max	Unit	
Characteristics	Symbol	Test C						
High-Level Input Voltage	VIH			2.7~3.6	2.0		v	
Low-Level Input Voltage	VIL			2.7~3.6	_	0.8	v	
			I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_		
High-Level Output Voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -12 mA	2.7	2.2	_	V	
			I _{OH} = -18 mA	3.0	2.4	_		
			I _{OH} =24 mA	3.0	2.2	_		
				I _{OL} = 100 μA	2.7~3.6	_	0.2	
Low Lovel Output Valtage	Max		I _{OL} = 12 mA	2.7	_	0.4	v	
Low-Level Output Voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 18 mA	3.0	_	0.4	v	
			I _{OL} = 24 mA	3.0	_	0.55		
Input Leakage Current	I _{IN}	V _{IN} = 0~3.6 V		2.7~3.6	_	±10.0	μA	
Power-off Leakage Current	IOFF	V _{IN} or V _{OUT} = 0~	V _{IN} or V _{OUT} = 0~3.6 V		_	10.0	μA	
Quieseent Supply Current	1	$V_{IN} = V_{CC}$ or GN	V _{IN} = V _{CC} or GND		_	20.0		
Quiescent Supply Current	ICC	$V_{CC} \leq V_{IN} \leq 3.6$	$V_{CC} \leq V_{IN} \leq 3.6 V$			±20.0	μA	
Increase in I _{CC} per Input	Δlcc	$V_{IH} = V_{CC} - 0.6$ V	/	2.7~3.6		750		

DC Electrical Characteristics (Ta = -40~85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristics	Symbol	Test C	Condition	V _{CC} (V)	Min	Max	Unit				
High-Level Input Voltage	V _{IH}			2.3~2.7	1.6	_	V				
Low-Level Input Voltage	V _{IL}			2.3~2.7	_	0.7	v				
			I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	_					
High-Level Output Voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$		VIN = VIH or VII	VIN = VIH or VII	V _{IN} = V _{IH} or V _{II}	I _{OH} = -6 mA	2.3	2.0	_	V
	-			I _{OH} = -12 mA	2.3	1.8					
			I _{OH} = -18 mA	2.3	1.7						
			I _{OL} = 100 μA	2.3~2.7		0.2	v				
Low-Level Output Voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 12 mA	2.3		0.4	v			
			I _{OL} = 18 mA	2.3		0.6					
Input Leakage Current	l _{IN}	V _{IN} = 0~3.6 V		2.3~2.7		±10.0	μA				
Power-off Leakage Current	I _{OFF}	V _{IN} or V _{OUT} = 0~3.6 V		0	_	10.0	μA				
Quiescent Supply Current	1	$V_{IN} = V_{CC}$ or GNI	$V_{IN} = V_{CC}$ or GND			20.0					
Quiescent Supply Current	Icc	$V_{CC} \leq V_{IN} \leq 3.6$	$V_{CC} \leq V_{IN} \leq 3.6 V$		_	±20.0	μA				

DC Electrical Characteristics (Ta = $-40 \sim 85^{\circ}$ C, 1.4 V \leq V_{CC} < 2.3 V)

Characteristics	Symbol	Test Condition			Min	Мах	Unit
Characteristics	Symbol	rest c	ondition	V _{CC} (V)	IVIIII	Max	Onit
High-Level Input Voltage	V _{IH}	-	_	1.4~2.3	V _{CC} × 0.7	_	V
Low-Level Input Voltage	VIL	-	_			V _{CC} × 0.13	v
High-Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.4	V _{CC} - 0.2	_	V
			I _{OH} = -4 mA	1.4	1.0		
Low-Level Output Voltage	Vol	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.4		0.2	V
	VOL	VIN - VIH OL VIL	I _{OL} = 4 mA	1.4		0.3	v
Input Leakage Current	I _{IN}	V _{IN} = 0~3.6 V		1.4		±10.0	μA
Power-off Leakage Current	I _{OFF}	V_{IN} or $V_{OUT} = 0 \sim 3.6 V$		0		10.0	μA
Quiescent Supply Current		$V_{IN} = V_{CC}$ or GND		1.4	_	20.0	
	Icc	$V_{CC} \leq V_{IN} \leq 3.6$	€V	1.4		±20.0	μA

AC Electrical Characteristics (Ta = $-40 \sim 85^{\circ}$ C, input t_r = t_f = 2.0 ns)

Characteristics	Symbol	Test Condition V _{CC} (V)		Min	Max	Unit									
				1.5 ± 0.1	1.8	10.0									
			C _L =15pF,	1.8 ± 0.15	1.5	8.0	ns								
			$R_L=1M\Omega$	$R_L = 1M\Omega$	2.5 ± 0.2	0.8	3.9	115							
Propagation delay time	' (Figuro 1 and	t _{pLH} (Figure 1 op)	t _{pLH} (Figure 1	t _{pLH}	t _{pLH}	t _{pLH}	t _{pLH}	t _{pLH}	t _{pLH}	(Figure 1 and 2)		$\textbf{3.3}\pm\textbf{0.3}$	0.6	3.3	
$(A \text{ or } \overline{G} - Y0 \text{ or } Y1)$				1.5 ± 0.1	2.0	13.0									
			C _L =30pF, R _L =500 Ω	$\textbf{1.8} \pm \textbf{0.15}$	1.8	9.5	ns								
				2.5 ± 0.2	1.2	5.0	115								
				3.3 ± 0.3	1.0	4.0									

For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition			TYP.	Unit
Characteristics	Symbol	Test Condition		V _{CC} (V)	IIF.	Unit
Input Capacitance	C _{IN}	—		1.8, 2.5, 3.3	6	pF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10 MHz	(Note 11)	1.8, 2.5, 3.3	20	pF

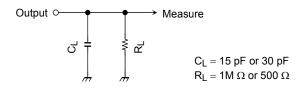
Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

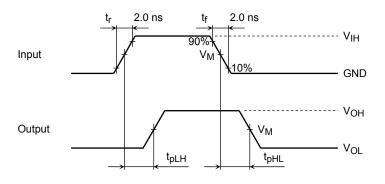
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AC test circuit Figure 1



AC wave forms

Figure 2 t_{pLH}, t_{pHL}



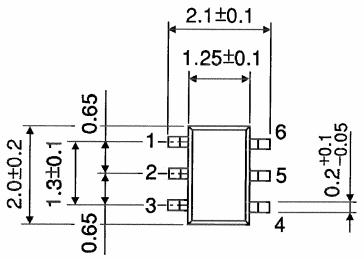
Symbol	V _{CC}					
Symbol	$3.3\pm0.3~V$	$2.5\pm0.2~\text{V}$	$1.8\pm0.15~V$	$1.5\pm0.1\;V$		
VIH	2.7 V	V _{CC}	V _{CC}	V _{CC}		
VM	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2		

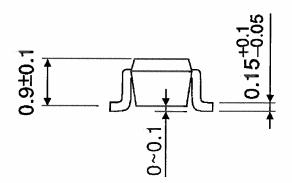
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Unit: mm

Package Dimensions

SSOP6-P-0.65A





Weight: 0.0068 g (typ.)

2007-11-01

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20070701-EN GENERAL

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